



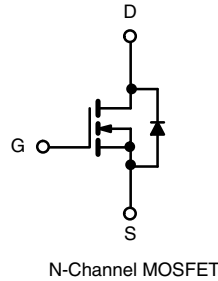
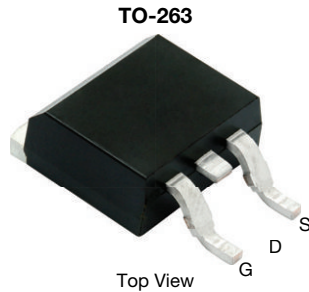
Automotive N-Channel 150 V (D-S) 175 °C MOSFET



| PRODUCT SUMMARY | |
|---|--------|
| V _{DS} (V) | 150 |
| R _{DS(on)} (Ω) at V _{GS} = 10 V | 0.052 |
| I _D (A) | 25 |
| Configuration | Single |
| Package | TO-263 |

FEATURES

- TrenchFET® power MOSFET
- Package with low thermal resistance
- 100 % R_g and UIS tested
- AEC-Q101 qualified ^d
- Material categorization:
for definitions of compliance please see www.vishay.com/doc?99912



ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)

| PARAMETER | SYMBOL | LIMIT | UNIT | |
|---|-----------------------------------|-------------------------|------|----|
| Drain-Source Voltage | V _{DS} | 150 | V | |
| Gate-Source Voltage | V _{GS} | ± 20 | | |
| Continuous Drain Current | I _D | T _C = 25 °C | A | |
| | | T _C = 125 °C | | 16 |
| Continuous Source Current (Diode Conduction) ^a | I _S | 50 | | |
| Pulsed Drain Current ^b | I _{DM} | 65 | | |
| Single Pulse Avalanche Energy | L = 0.1 mH | I _{AS} | | 30 |
| Single Pulse Avalanche Current | | E _{AS} | | 45 |
| Maximum Power Dissipation ^b | P _D | T _C = 25 °C | 107 | W |
| | | T _C = 125 °C | 35 | |
| Operating Junction and Storage Temperature Range | T _J , T _{stg} | -55 to +175 | °C | |

THERMAL RESISTANCE RATINGS

| PARAMETER | SYMBOL | LIMIT | UNIT |
|--------------------------|-------------------|-------|------|
| Junction-to-Ambient | R _{thJA} | 40 | °C/W |
| Junction-to-Case (Drain) | R _{thJC} | 1.4 | |

Notes

- Package limited.
- Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %.
- When mounted on 1" square PCB (FR4 material).
- Parametric verification ongoing.



| SPECIFICATIONS (T _C = 25 °C, unless otherwise noted) | | | | | | | |
|--|---------------------|--|--|------|-------|-------|------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNIT |
| Static | | | | | | | |
| Drain-Source Breakdown Voltage | V _{DS} | V _{GS} = 0 V, I _D = 250 μA | | 150 | - | - | V |
| Gate-Source Threshold Voltage | V _{GS(th)} | V _{DS} = V _{GS} , I _D = 250 μA | | 2.5 | 3 | 4 | |
| Gate-Source Leakage | I _{GSS} | V _{DS} = 0 V, V _{GS} = ± 20 V | | - | - | ± 100 | nA |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{GS} = 0 V | V _{DS} = 150 V | - | - | 1 | μA |
| | | V _{GS} = 0 V | V _{DS} = 150 V, T _J = 125 °C | - | - | 50 | |
| | | V _{GS} = 0 V | V _{DS} = 150 V, T _J = 175 °C | - | - | 250 | |
| On-State Drain Current ^a | I _{D(on)} | V _{GS} = 10 V | V _{DS} ≥ 5 V | 30 | - | - | A |
| Drain-Source On-State Resistance ^a | R _{DS(on)} | V _{GS} = 10 V | I _D = 15 A | - | 0.041 | 0.052 | Ω |
| | | V _{GS} = 10 V | I _D = 15 A, T _J = 125 °C | - | - | 0.106 | |
| | | V _{GS} = 10 V | I _D = 15 A, T _J = 175 °C | - | - | 0.138 | |
| Forward Transconductance ^b | g _{fs} | V _{DS} = 15 V, I _D = 15 A | | - | 33 | - | S |
| Dynamic ^b | | | | | | | |
| Input Capacitance | C _{iss} | V _{GS} = 0 V | V _{DS} = 25 V, f = 1 MHz | - | 1886 | 2360 | pF |
| Output Capacitance | C _{oss} | | | - | 215 | 270 | |
| Reverse Transfer Capacitance | C _{rss} | | | - | 97 | 125 | |
| Total Gate Charge ^c | Q _g | V _{GS} = 10 V | V _{DS} = 75 V, I _D = 25 A | - | 34 | 51 | nC |
| Gate-Source Charge ^c | Q _{gs} | | | - | 14.5 | - | |
| Gate-Drain Charge ^c | Q _{gd} | | | - | 5.4 | - | |
| Gate Resistance | R _g | f = 1 MHz | | 0.35 | 1.0 | 3.2 | Ω |
| Turn-On Delay Time ^c | t _{d(on)} | V _{DD} = 75 V, R _L = 3 Ω I _D ≅ 25 A, V _{GEN} = 10 V, R _g = 1 Ω | | - | 11 | 17 | ns |
| Rise Time ^c | t _r | | | - | 21 | 33 | |
| Turn-Off Delay Time ^c | t _{d(off)} | | | - | 20 | 30 | |
| Fall Time ^c | t _f | | | - | 12 | 20 | |
| Source-Drain Diode Ratings and Characteristics ^b | | | | | | | |
| Pulsed Current ^a | I _{SM} | | | - | - | 65 | A |
| Forward Voltage | V _{SD} | I _F = 20 A, V _{GS} = 0 V | | - | 0.85 | 1.5 | V |

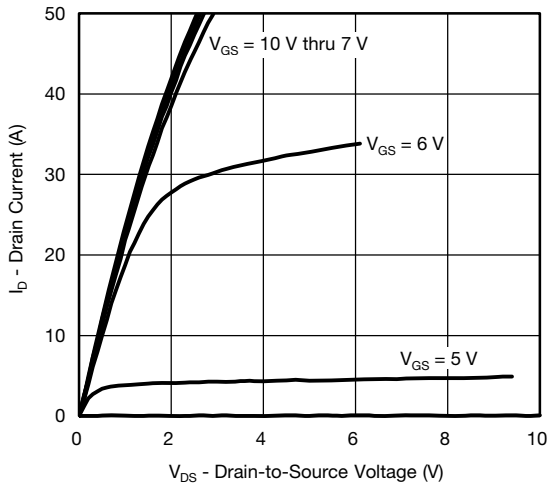
Notes

- a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %.
b. Guaranteed by design, not subject to production testing.
c. Independent of operating temperature.

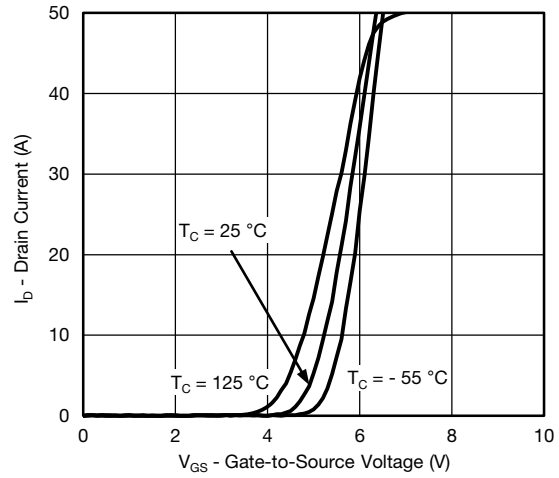
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



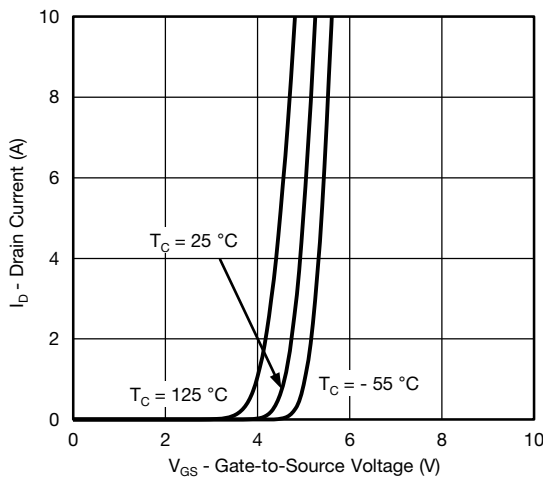
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



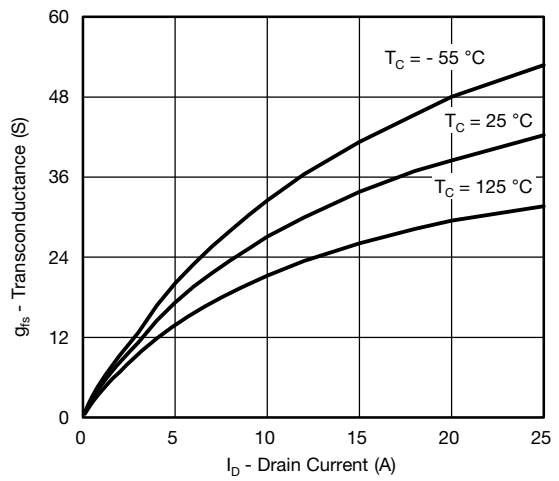
Output Characteristics



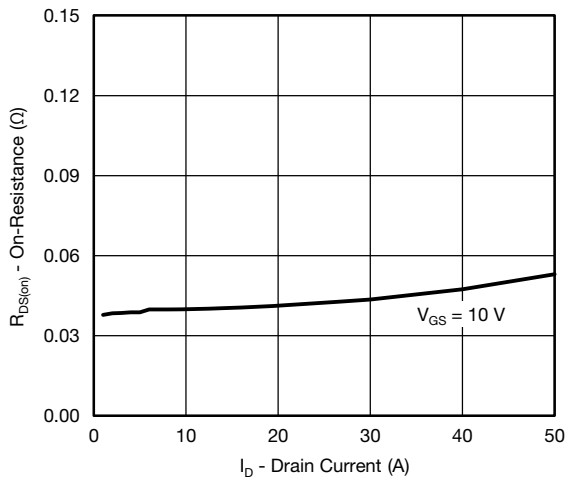
Transfer Characteristics



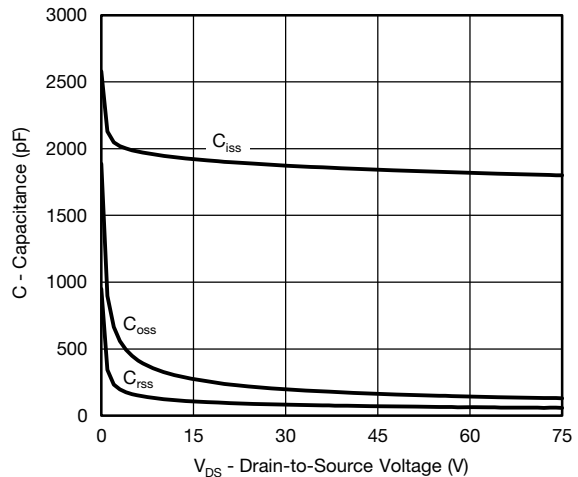
Transfer Characteristics



Transconductance



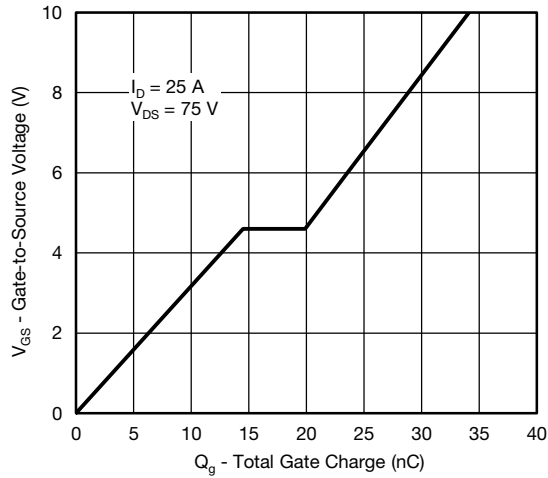
On-Resistance vs. Drain Current



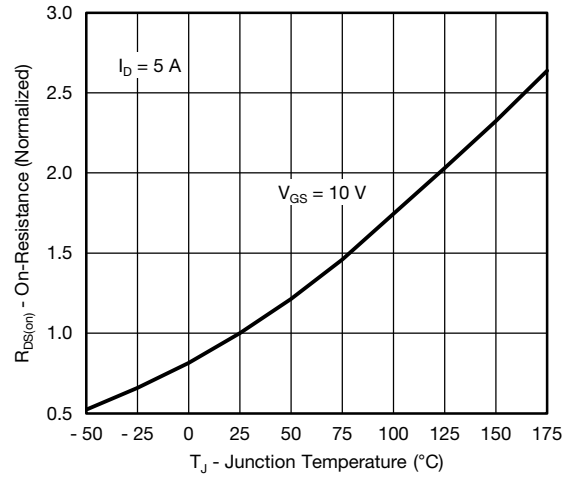
Capacitance



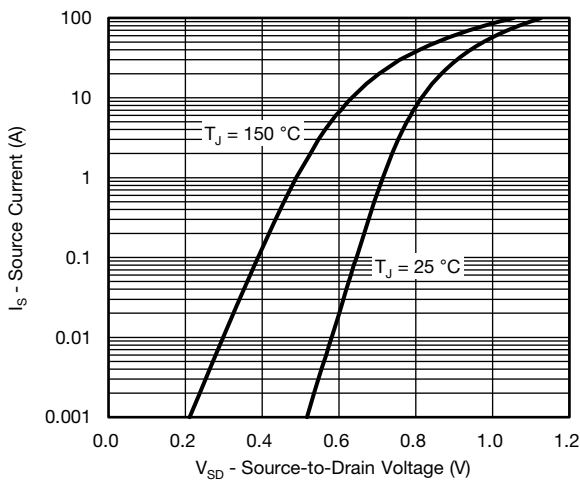
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



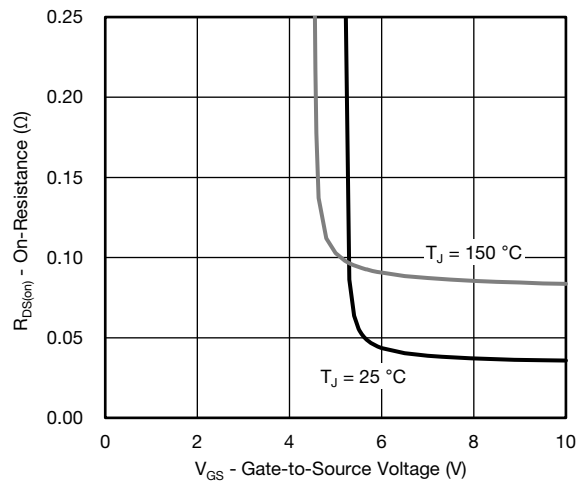
Gate Charge



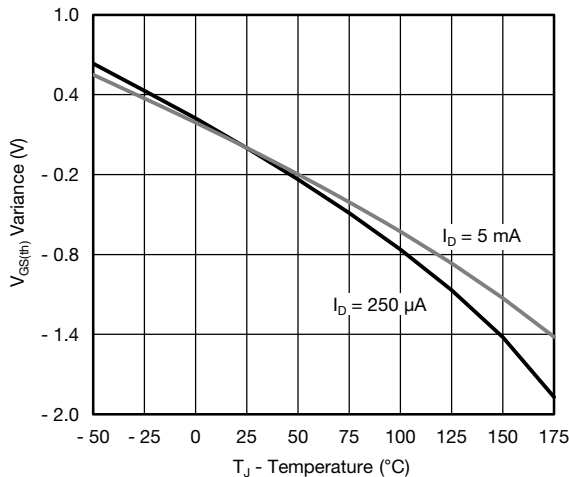
On-Resistance vs. Junction Temperature



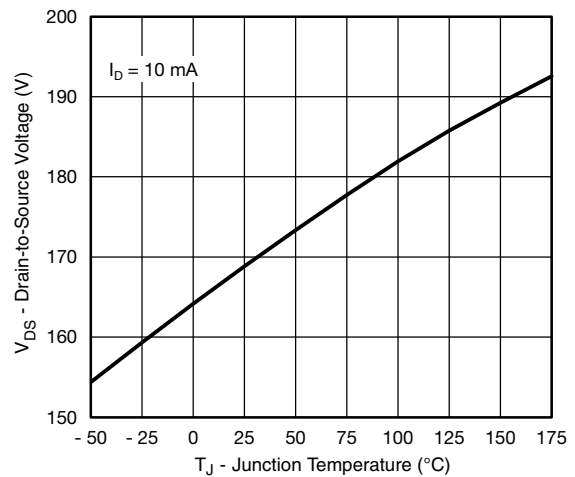
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



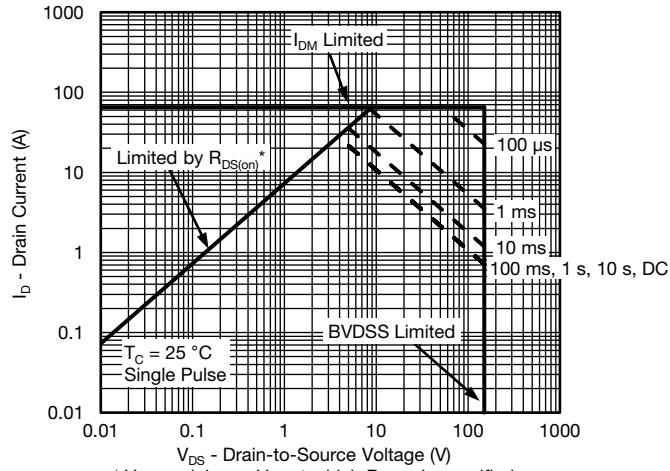
Threshold Voltage



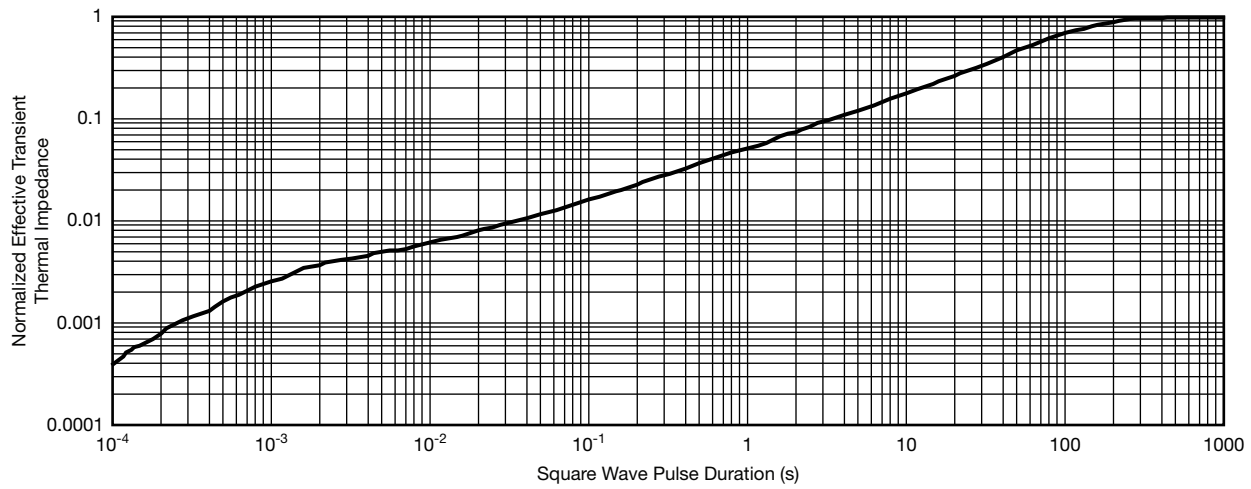
Drain Source Breakdown vs. Junction Temperature



THERMAL RATINGS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



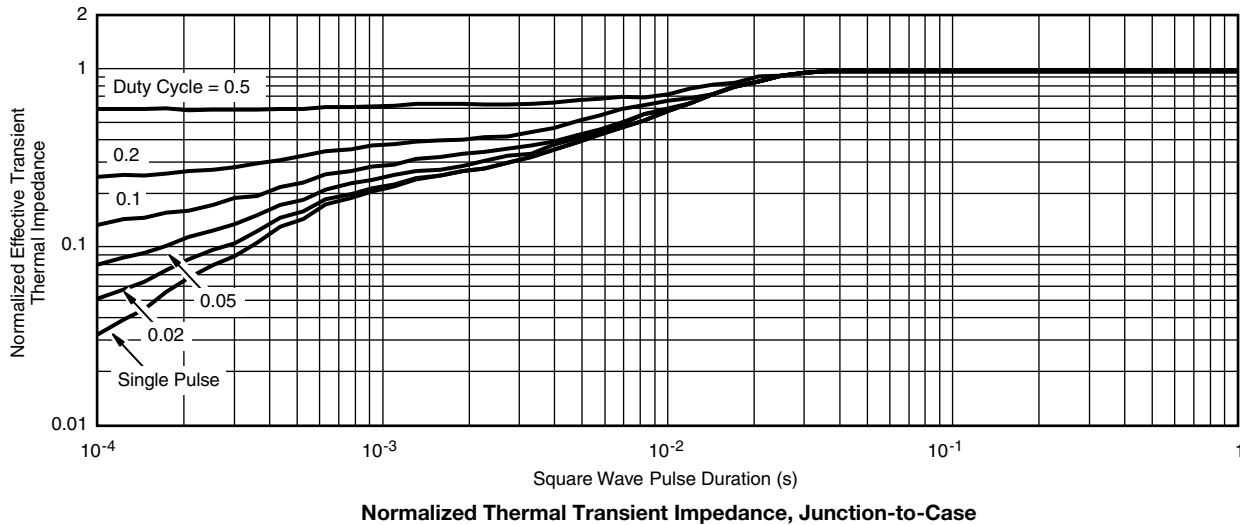
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction to Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction to Case (25 °C)
 are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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| REVISION HISTORY ^a | | |
|-------------------------------|-----------|---|
| REVISION | DATE | DESCRIPTION OF CHANGE |
| D | 08-Aug-15 | • R_g , C_{RSS} , t_r and t_f changed |

Note

a. As of April 2014



D²PAK / TO-263 and TO-262

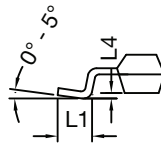
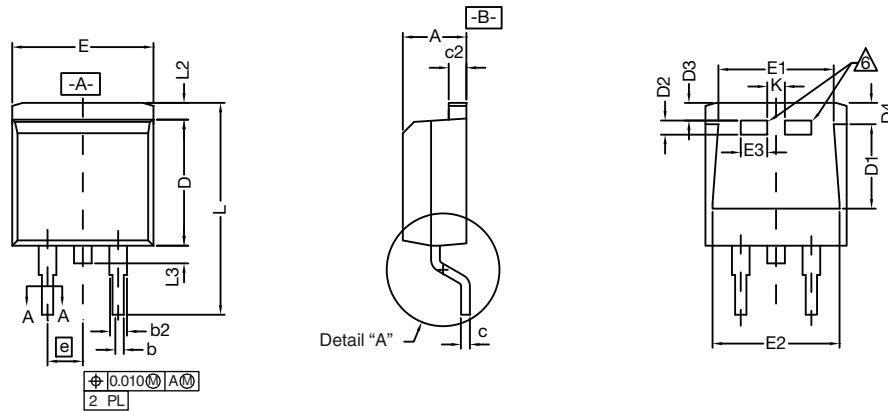
Ordering codes for the SQ rugged series power MOSFETs in the D²PAK / TO-263 and TO-262 packages:

| DATASHEET PART NUMBER | OLD ORDERING CODE ^a | NEW ORDERING CODE |
|-----------------------|--------------------------------|--------------------|
| SQM100N04-2m7 | SQM100N04-2M7-GE3 | SQM100N04-2M7_GE3 |
| SQM100N10-10 | SQM100N10-10-GE3 | SQM100N10-10_GE3 |
| SQM110N05-06L | SQM110N05-06L-GE3 | SQM110N05-06L_GE3 |
| SQM110P06-8m9L | SQM110P06-8M9L-GE3 | SQM110P06-8M9L_GE3 |
| SQM120N02-1m3L | SQM120N02-1M3L-GE3 | SQM120N02-1M3L_GE3 |
| SQM120N03-1m5L | SQM120N03-1M5L-GE3 | SQM120N03-1M5L_GE3 |
| SQM120N04-1m7 | SQM120N04-1M7-GE3 | SQM120N04-1M7_GE3 |
| SQM120N04-1m7L | SQM120N04-1M7L-GE3 | SQM120N04-1M7L_GE3 |
| SQM120N04-1m9 | SQM120N04-1M9-GE3 | SQM120N04-1M9_GE3 |
| SQM120N06-06 | SQM120N06-06-GE3 | SQM120N06-06_GE3 |
| SQM120N06-3m5L | SQM120N06-3M5L-GE3 | SQM120N06-3M5L_GE3 |
| SQM120N10-09 | SQM120N10-09-GE3 | SQM120N10-09_GE3 |
| SQM120N10-3m8 | SQM120N10-3M8-GE3 | SQM120N10-3M8_GE3 |
| SQM120P04-04L | SQM120P04-04L-GE3 | SQM120P04-04L_GE3 |
| SQM120P06-07L | SQM120P06-07L-GE3 | SQM120P06-07L_GE3 |
| SQM200N04-1m1L | SQM200N04-1M1L-GE3 | SQM200N04-1M1L_GE3 |
| SQM200N04-1m7L | SQM200N04-1M7L-GE3 | SQM200N04-1M7L_GE3 |
| SQM200N04-1m8 | SQM200N04-1M8-GE3 | SQM200N04-1M8_GE3 |
| SQM25N15-52 | SQM25N15-52-GE3 | SQM25N15-52_GE3 |
| SQM35N30-97 | SQM35N30-97-GE3 | SQM35N30-97_GE3 |
| SQM40N10-30 | SQM40N10-30-GE3 | SQM40N10-30_GE3 |
| SQM40N15-38 | SQM40N15-38-GE3 | SQM40N15-38_GE3 |
| SQM40P10-40L | SQM40P10-40L-GE3 | SQM40P10-40L_GE3 |
| SQM47N10-24L | SQM47N10-24L-GE3 | SQM47N10-24L_GE3 |
| SQM50020EL | - | SQM50020EL_GE3 |
| SQM50N04-4m0L | SQM50N04-4M0L-GE3 | SQM50N04-4M0L_GE3 |
| SQM50N04-4m1 | SQM50N04-4M1-GE3 | SQM50N04-4M1_GE3 |
| SQM50P03-07 | SQM50P03-07-GE3 | SQM50P03-07_GE3 |
| SQM50P04-09L | SQM50P04-09L-GE3 | SQM50P04-09L_GE3 |
| SQM50P06-15L | SQM50P06-15L-GE3 | SQM50P06-15L_GE3 |
| SQM50P08-25L | SQM50P08-25L-GE3 | SQM50P08-25L_GE3 |
| SQM60N06-15 | SQM60N06-15-GE3 | SQM60N06-15_GE3 |
| SQM60N20-35 | SQM60N20-35-GE3 | SQM60N20-35_GE3 |
| SQM85N15-19 | SQM85N15-19-GE3 | SQM85N15-19_GE3 |
| SQV120N10-3m8 | SQV120N10-3m8-GE3 | SQV120N10-3m8_GE3 |
| SQV120N06-4m7L | - | SQV120N06-4m7L_GE3 |

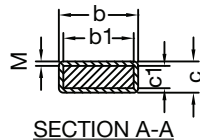
Note

a. Old ordering code is obsolete and no longer valid for new orders

TO-263 (D²PAK): 3-LEAD



DETAIL A (ROTATED 90°)



| DIM. | INCHES | | MILLIMETERS | | |
|---------------------------------|------------|-------|-------------|--------|-------|
| | MIN. | MAX. | MIN. | MAX. | |
| A | 0.160 | 0.190 | 4.064 | 4.826 | |
| b | 0.020 | 0.039 | 0.508 | 0.990 | |
| b1 | 0.020 | 0.035 | 0.508 | 0.889 | |
| b2 | 0.045 | 0.055 | 1.143 | 1.397 | |
| c* | Thin lead | 0.013 | 0.018 | 0.330 | 0.457 |
| | Thick lead | 0.023 | 0.028 | 0.584 | 0.711 |
| c1 | Thin lead | 0.013 | 0.017 | 0.330 | 0.431 |
| | Thick lead | 0.023 | 0.027 | 0.584 | 0.685 |
| c2 | 0.045 | 0.055 | 1.143 | 1.397 | |
| D | 0.340 | 0.380 | 8.636 | 9.652 | |
| D1 | 0.220 | 0.240 | 5.588 | 6.096 | |
| D2 | 0.038 | 0.042 | 0.965 | 1.067 | |
| D3 | 0.045 | 0.055 | 1.143 | 1.397 | |
| D4 | 0.044 | 0.052 | 1.118 | 1.321 | |
| E | 0.380 | 0.410 | 9.652 | 10.414 | |
| E1 | 0.245 | - | 6.223 | - | |
| E2 | 0.355 | 0.375 | 9.017 | 9.525 | |
| E3 | 0.072 | 0.078 | 1.829 | 1.981 | |
| e | 0.100 BSC | | 2.54 BSC | | |
| K | 0.045 | 0.055 | 1.143 | 1.397 | |
| L | 0.575 | 0.625 | 14.605 | 15.875 | |
| L1 | 0.090 | 0.110 | 2.286 | 2.794 | |
| L2 | 0.040 | 0.055 | 1.016 | 1.397 | |
| L3 | 0.050 | 0.070 | 1.270 | 1.778 | |
| L4 | 0.010 BSC | | 0.254 BSC | | |
| M | - | 0.002 | - | 0.050 | |
| ECN: T13-0707-Rev. K, 30-Sep-13 | | | | | |
| DWG: 5843 | | | | | |

Notes

- Plane B includes maximum features of heat sink tab and plastic.
- No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- Pin-to-pin coplanarity max. 4 mils.
- *: Thin lead is for SUB, SYB.
Thick lead is for SUM, SYM, SQM.
- Use inches as the primary measurement.
- This feature is for thick lead.

RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads
Dimensions in Inches/(mm)

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